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# ATOM120

## *4-bit Turbo Microcontroller*

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# 1 ATOM120 Overview

## 1.1 General Description

**ATOM120** is a 4-bit reduced 8051 Microcontroller.

**ATOM120** has 17 or 13 programmable I/O ports, Watchdog timer, POR (Power-On Reset), built-in I.R. LED Driver, and LVD (Low Voltage Detector) as peripherals. In addition, it contains an internal precision oscillator, which can generate the 3.64 MHz system clock signal instead of a crystal oscillator.

**ATOM120** operates over the extended -20°C to +70°C temperature range, and is available in the 20-pin SOP, 20-pin TSSOP, 16-pin TSSOP package.

## 1.2 Features

- ◆ CPU
  - ✓ 4-bit reduced 8051 architecture
  - ✓ Continuous program addressing, not paged.
  - ✓ 51 instructions including push, pop and logic inst.
  - ✓ Instruction cycle :  $F_{SYS}/6$
  - ✓ Multi-level subroutine nesting with RAM based stack.
- ◆ Program Memory (MTP)
  - ✓ 4K Bytes (4,096 X 8 bits)
  - ✓ Multi-programmable by 1K Bytes, 2K Bytes or 4K Bytes
  - ✓ ISP (In System Programming) of MTP
- ◆ Data RAM : 48 nibbles (including stack)
- ◆ I/O Ports
  - ✓ P0 : 4-bit parallel input
  - ✓ P1 : 2-bit parallel input, 2-bit parallel I/O
  - ✓ P2 : 4-bit parallel I/O, Bit-selectable output
  - ✓ P3 : 2-bit parallel I/O, Bit-selectable output
  - ✓ P4 : 3-bit Parallel/bit-selectable Output

- ◆ REM output (Remote control transmitter)
  - ✓ Built-in Transistor for I.R. LED Drive
  - ✓  $I_{OL} = 250 \text{ mA}$  (Max.) at  $V_{DD} = 3\text{V}$  and  $V_O = 0.3\text{V}$
- ◆ Carrier Pulse Generation : 8 types
- ◆ Built-in Oscillator
  - ✓ Crystal/Ceramic resonator (for 1.2V application)
  - ✓ Internal Precision Oscillator : 3.64 MHz (Max.  $\pm 2\%$ , Typ.  $\pm 1\%$ )
- ◆ Built-in Reset
  - ✓ Power-on Reset, Power-fail Reset
  - ✓ WDT (Watch-Dog Timer) Reset
  - ✓ Clock switching reset
- ◆ Power Management
  - ✓ Power-down (stop) mode
  - ✓ Release stop by input changes
- ◆ Power Consumption (TBD)
  - ✓ Stop mode : 1  $\mu\text{A}$  (Typ.) at 3.0V
  - ✓ Normal mode : 400  $\mu\text{A}$  (Typ.) at 2.0V,  $F_{OSC} = 4 \text{ MHz}$
- ◆ Operating frequency vs. voltage
  - ✓ Max.  $F_{SYS} = 4 \text{ MHz}$  ( $1.8 \text{ V} \leq V_{DD} \leq 3.6\text{V}$ )
  - ✓ Max.  $F_{SYS} = 0.5 \text{ MHz}$  ( $1.2 \text{ V} \leq V_{DD} \leq 1.8\text{V}$ )
- ◆ Operating temperature :  $-20 \text{ }^\circ\text{C} \sim 70 \text{ }^\circ\text{C}$
- ◆ ESD protection
  - ✓ HBM : 2,000V (JESD22-A114E)
  - ✓ MM : 200V (JESD22-A115-A)
  - ✓ CDM : 800V (JESD22-C101-C)
- ◆ Latch-up protection up to  $\pm 200\text{mA}$
- ◆ Package
  - ✓ 20-pin SOIC (JEDEC)
  - ✓ 20-pin TSSOIC
  - ✓ 16-pin TSSOIC

### 1.3 Applications

- ◆ Remote Controller

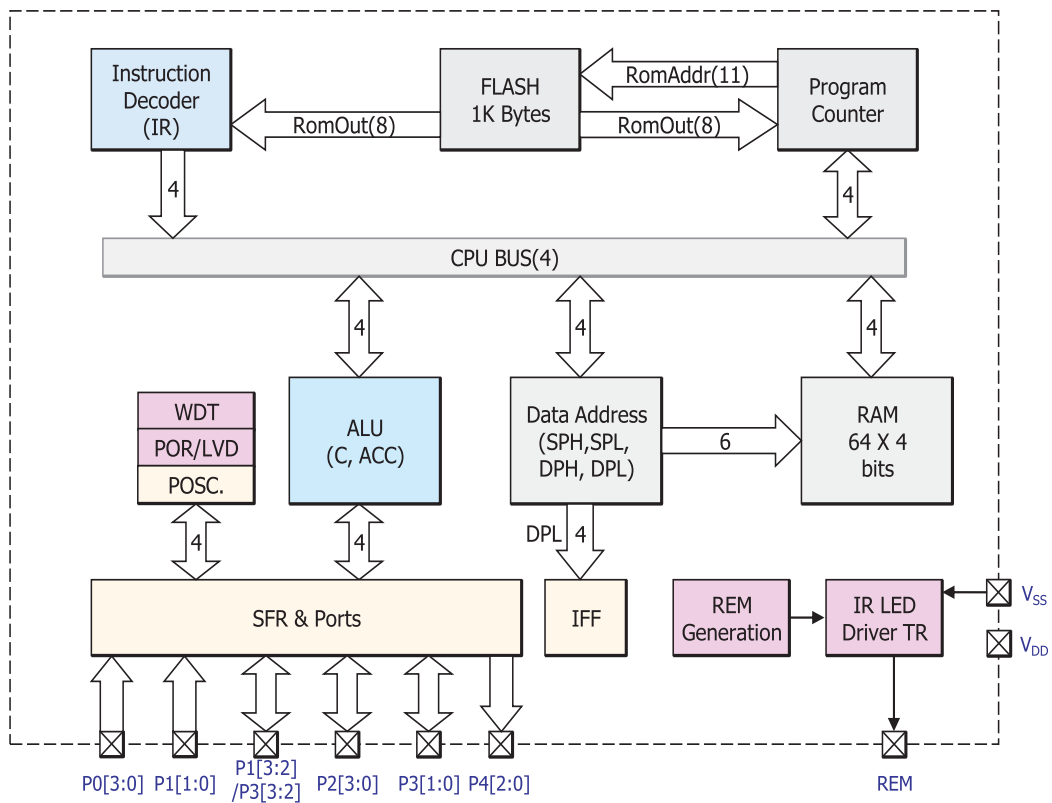
## 1.4 Product Family Guide

Product	Mask-ROM [Byte]	EPROM [Byte]	RAM [Nibble]	I/O Pins	Package	Other Peripherals
<b>ATOM120</b>	-	<b>4k</b>	<b>48</b>	<b>17</b> <b>17</b> <b>13</b>	20-SOP 20-TSSOP 16-TSSOP	WDT ISP LVD POR POSC I.R. LED Driver

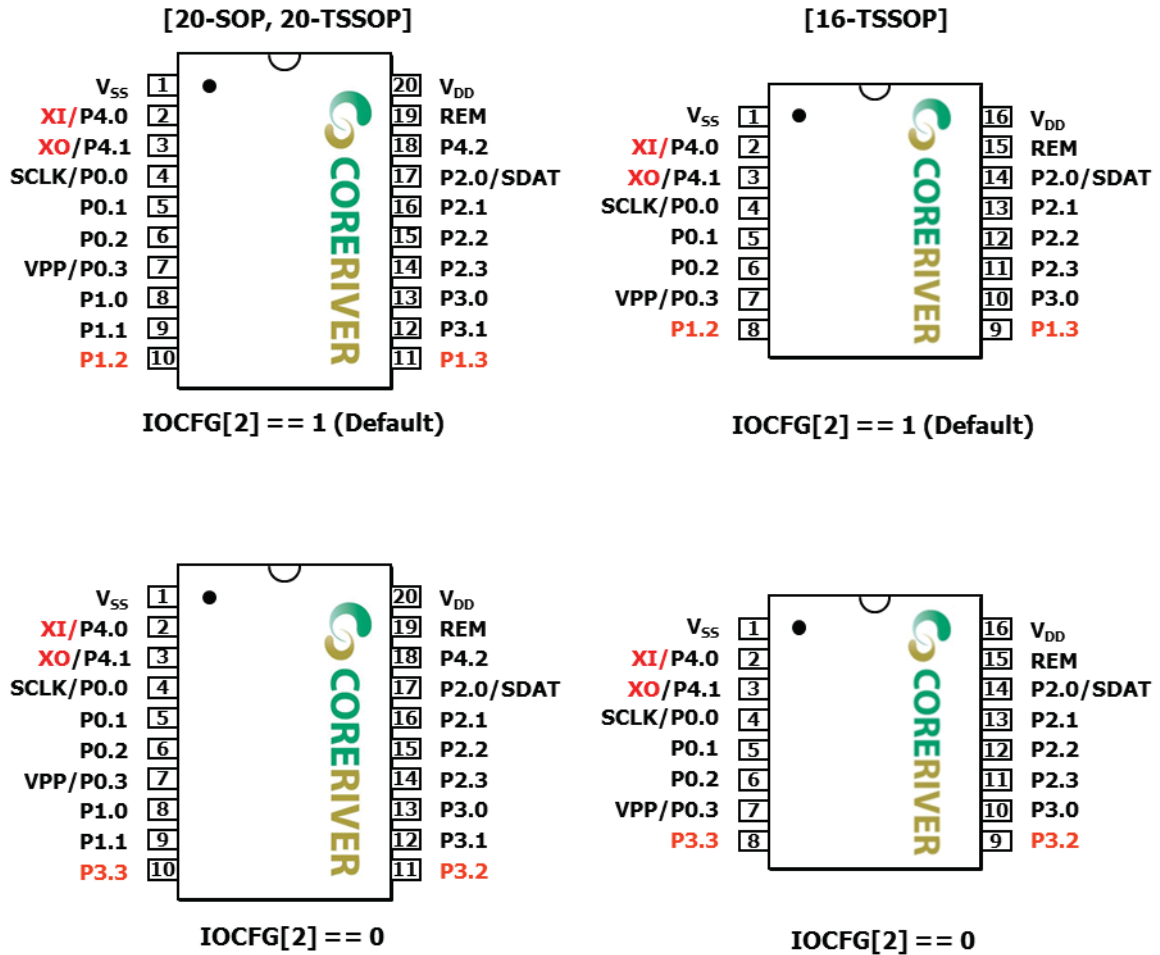
## 2 Block Diagram

Figure shows the block diagram of **ATOM120**. Programs reside in the internal program memory (Embedded Flash Memory). Data are read from or written to data memory (SRAM) or special function registers (SFRs).

The internal registers of **ATOM120** are configured as part of the on-chip RAM: therefore each register has an address.



### 3 Pin Configuration



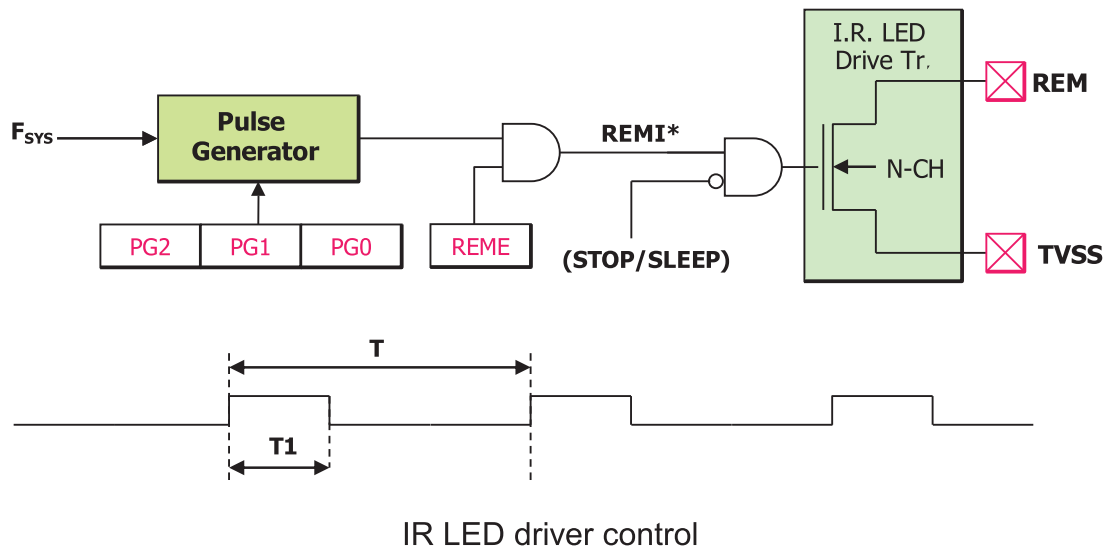
20-pin & 16-pin Package Diagram

## 4 Pin Description

Symbol	Direction	Description	Remark
V <sub>DD</sub>	Power	Power Supply	
V <sub>SS</sub>	Power	Ground	
REM	Output	Output for IR LED drive Transistor. The transistor is n-channel device.	
P4[2:0]	Output	Parallel open-drain Output port. If configured, P4[1:0] is used as XTAL oscillator PADS.	P4.0 : XI P4.1 : XO
P0[3:0]	Input	Parallel Input port with internal pull-up TR. The STOP mode is released by "L" input of each pin. P0[0] and P0[3] are also used for ISP of OTP memory.	P0.0 : SCLK P0.3 : VPP
P1[1:0]	Input	Parallel Input port with internal pull-up TR. The STOP mode is released by "L" input of each pin.	
P1[3:2]	Input/Output	Parallel Input/Output port. (If IOCFG[2] is set. Default I/O map.) Schmitt Trigger input and open-drain output with internal pull-up TR. The STOP mode is released by "L" input of each pin while the port register contains "H".	
P2[3:0]	Input/Output	Parallel Input/Output port. Each bit can be individually set or cleared. Schmitt Trigger input and open-drain output with internal pull-up TR. P2[0] is also used for ISP of OTP memory.	P2.0 : SDAT
P3[1:0]	Input/Output	Parallel Input/Output port. Each bit can be individually set or cleared. Schmitt Trigger input and open-drain output with internal pull-up TR.	
P3[3:2]	Input/Output	Parallel Input/Output port. (If IOCFG[2] is cleared.) Schmitt Trigger input and open-drain output with internal pull-up TR.	

## 5 Carrier frequency generation

The ATOM1.1 family can drive an IR LED for remote controller application. It supports 7 carrier frequencies for data transmission. The REMC register is used for control of the IR LED driver and the carrier frequency.



The IR LED driver is a n-channel MOS transistor. The REM output is the inverse of the REMI\* signal. The IR LED is turned on when REMI\* is high.

REME	PG2	PG1	PG0	Transmission Control (REMI)
0	X	X	X	0 (Disable)
1	0	0	0	$1/T = F_{osc}/12$ , $T1/T = 1/3$
1	0	0	1	$1/T = F_{osc}/8$ , $T1/T = 1/2$
1	0	1	0	$1/T = F_{osc}/12$ , $T1/T = 1/4$
1	0	1	1	1 (No carrier)
1	1	0	0	$1/T = F_{osc}/12$ , $T1/T = 1/2$
1	1	0	1	$1/T = F_{osc}/8$ , $T1/T = 1/4$
1	1	1	0	$1/T = F_{osc}/11$ , $T1/T = 4/11$
1	1	1	1	$1/T = F_{osc}/92$ , $T1/T = 1/2$

Carrier frequency selection



## 6 Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
$V_{DD}$	DC supply voltage	-0.5 to $V_{DD} + 0.5$	V
$V_{IN}$	DC input voltage	-0.5 to $V_{DD} + 0.5$	V
$V_{OUT}$	DC output Voltage	-0.5 to $V_{DD} + 0.5$	V
$I_{OH}$	DC output high current	One I/O pin active: -25	mA
		All I/O pins active: -100	mA
$I_{OL}$	DC output low current	One I/O pin active: 30	mA
		All I/O pins active: 150	mA
$T_{STG}$	Storage temperature	-55 to 125	°C

## 7 Recommended Operating Conditions

Symbol	Parameter	Rating	Unit
$V_{DD}$	DC supply voltage	1.8 to 3.6	V
$T_A$	Industrial temperature range	-20 to 70	°C

## 8 DC Characteristics

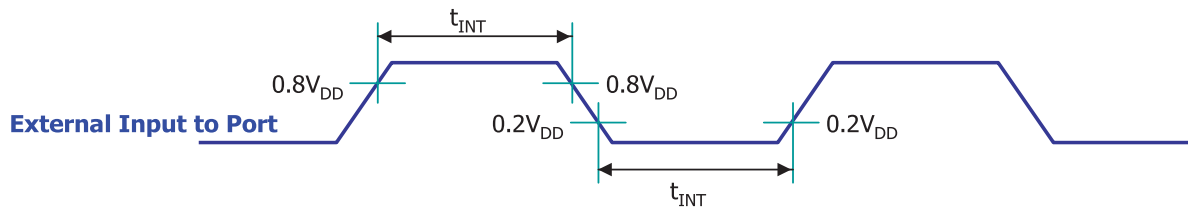
( $T_A = -20^{\circ}\text{C} \sim +70^{\circ}\text{C}$ ,  $V_{DD} = 1.2\text{V} \sim 3.6\text{V}$  unless otherwise specified)

Parameter	Symbol	Pin	Conditions	Value			Unit
				Min.	Typ.	Max.	
Input low voltage	$V_{IL1}$	P0, P1, P2, P3	$V_{DD} = 1.2\text{V} \sim 3.6\text{V}$	-0.5	-	$0.2V_{DD} - 0.1$	V
Input high voltage	$V_{IH1}$	P0, P1, P2, P3	$V_{DD} = 1.2\text{V} \sim 3.6\text{V}$	$0.2V_{DD} + 1.0$	-	$V_{DD} + 0.5$	V
Input high leakage current	$I_{IH}$	All pins except XI, XO	$V_{IN} = V_{DD}$	-1	-	+1	$\mu\text{A}$
Output low voltage	$V_{OL}$	P1[3:2], P2, P3, P4	$I_{OL} = 20\text{mA} @ V_{DD} = 3.6\text{V}$ ( $I_{OL} = 3\text{mA} @ V_{DD} = 1.8\text{V}$ )	-	-	$0.3V_{DD}$	V
Output low voltage	$V_{OL2}$	REM	$I_{OL} = 250\text{mA} @ V_{DD} = 3\text{V}$	-	-	0.3	V
Output high voltage	$V_{OH}$	P2 (push-pull output)	$I_{OH} = -15\text{mA} @ V_{DD} = 5\text{V}$	$0.7V_{DD}$	-	-	V
Output high voltage	$V_{OHP}$	Pull-up current	$I_{OHP} = -40\mu\text{A} @ V_{DD} = 3.6\text{V}$ ( $I_{OHP} = -15\mu\text{A} @ V_{DD} = 1.8\text{V}$ )	$0.7V_{DD}$	-	-	V
Pin capacitance	$C_{IO}$	All	$V_{DD} = 3.6\text{V}$	-	10	-	pF

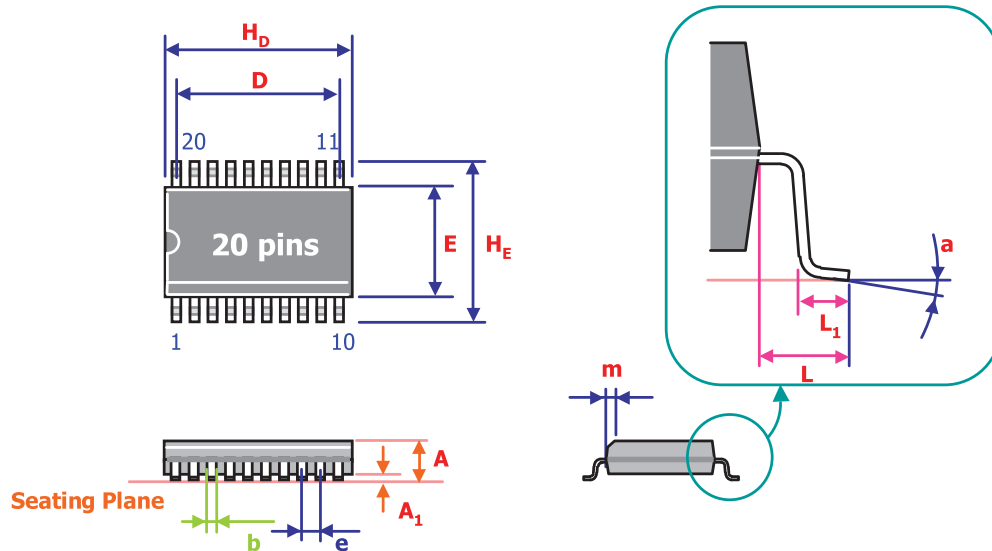
## 9 AC Characteristics

( $T_A = -20^\circ\text{C} \sim +70^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Pin	Conditions	Value			Unit
				Min.	Typ.	Max.	
Operating Frequency (Internal Clock)	$F_{\text{OSC}}$		$1.8\text{V} \leq V_{\text{DD}} \leq 3.6\text{V}$	-	3.64	-	MHz
			$1.2\text{V} \leq V_{\text{DD}} \leq 1.8\text{V}$	-	-	-	
Operating Frequency (External Clock)	$F_{\text{OSC}}$	XI, XO	$1.8\text{V} \leq V_{\text{DD}} \leq 3.6\text{V}$	-	-	4	MHz
			$1.2\text{V} \leq V_{\text{DD}} \leq 1.8\text{V}$	-	-	0.5	
System Frequency	$F_{\text{SYS}}$		$1.2\text{V} \leq V_{\text{DD}} \leq 3.6\text{V}$	1/8	-	1	$F_{\text{OSC}}$
External Input Width	$t_{\text{INT}}$	P0, P1, P2, P3	$1.2\text{V} \leq V_{\text{DD}} \leq 3.6\text{V}$	12	-	-	$F_{\text{SYS}}$



## 10 20-pin SOIC Package Dimension

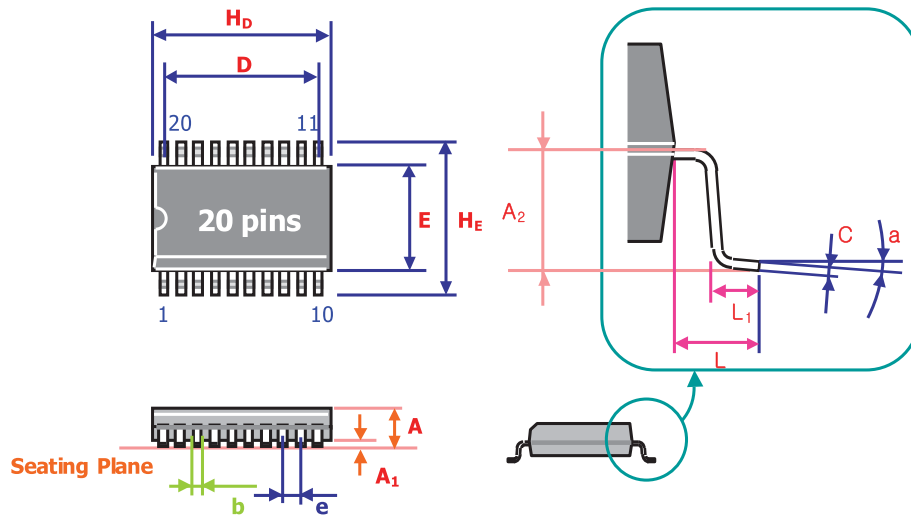


Symbol	Dimension in Inches			Dimension in mm		
	Min.	Nom.	Max.	Min.	Nom.	Max.
A	-	-	0.106	-	-	2.7
$A_1$	0.004	-	-	0.1	-	-
b	0.013	0.016	0.020	0.324	0.4	0.51
E	0.264	0.295	0.324	6.71	7.5	8.23
$H_D$	0.495	0.504	0.512	12.57	12.8	13
$H_E$	0.394	0.406	0.419	10.0	10.3	10.643
L	0.016	-	0.052	0.406	-	1.32
a	0°	-	8°	0°	-	8°
e	0.050 BSC			1.27 BSC		

### Notes:

1. Dimension D & E include mold mismatch and are determined at the mold parting line.
2. General appearance spec. should be based on final visual inspection spec.

## 11 20-pin TSSOIC Package Dimension

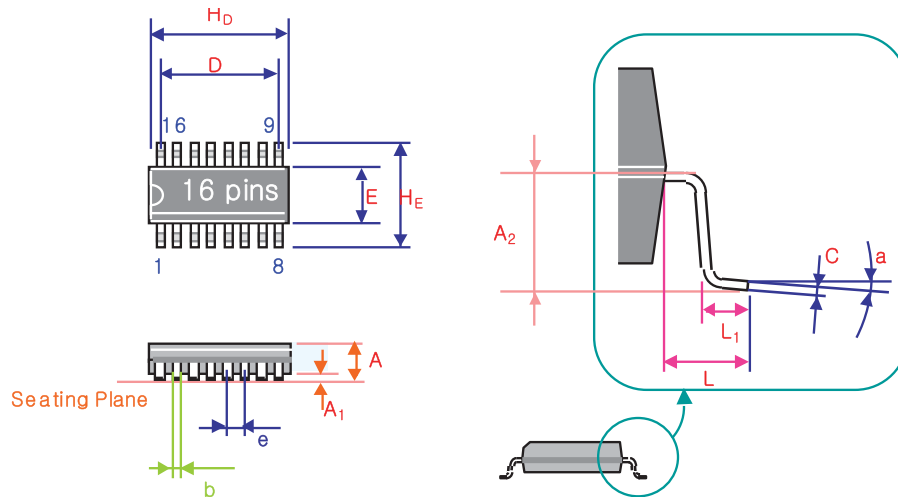


Symbol	Dimension in Inches			Dimension in mm		
	Min.	Nom.	Max.	Min.	Nom.	Max.
A	-	-	0.043	-	-	1.1
A <sub>1</sub>	0.001	-	0.006	0.020	-	0.150
A <sub>2</sub>	0.026	0.028	0.030	0.65	0.7	0.75
b	0.007	-	0.012	0.190	-	0.300
C	0.004	0.006	0.008	0.09	0.145	0.20
D	-	0.234	-	-	5.850	-
E	0.169	0.174	0.177	4.300	4.400	4.500
H <sub>D</sub>	0.252	0.254	0.259	6.400	6.500	6.600
H <sub>E</sub>	0.246	0.252	0.258	6.250	6.400	6.550
L	0.038	0.039	0.040	0.975	1.000	1.025
L <sub>1</sub>	0.020	0.024	0.028	0.500	0.600	0.700
a	1 <sup>°</sup>	-	7 <sup>°</sup>	1 <sup>°</sup>	-	7 <sup>°</sup>
e	0.026 BSC			0.65 BSC		

### Notes:

1. Dimension D & E include mold mismatch and are determined at the mold parting line.
2. General appearance spec. should be based on final visual inspection spec.

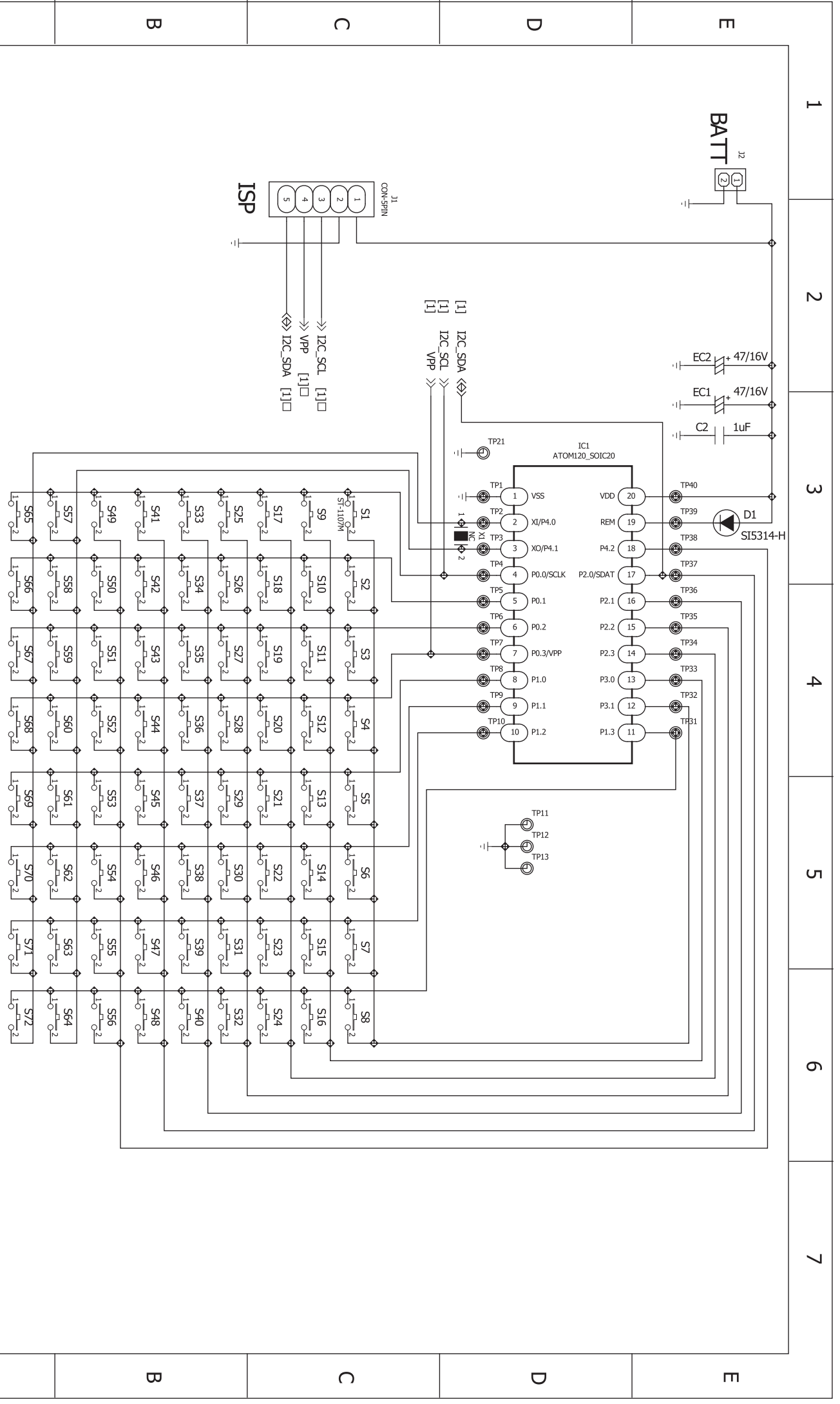
## 12 16-pin TSSOIC Package Dimension



Symbol	Dimension in Inches			Dimension in mm		
	Min.	Nom.	Max.	Min.	Nom.	Max.
A	0.037	0.039	0.041	0.95	1.00	1.05
A <sub>1</sub>	0.015	0.017	0.019	0.3865	0.4365	0.4865
A <sub>2</sub>	0.026	0.028	0.030	0.65	0.7	0.75
b	0.008	0.009	0.009	0.20	0.22	0.24
C	0.004	0.006	0.008	0.09	0.145	0.20
D	0.176	0.179	0.182	4.47	4.55	4.63
E	0.171	0.173	0.175	4.35	4.4	4.45
H <sub>D</sub>	0.200	0.202	0.204	5.077	5.127	5.177
H <sub>E</sub>	0.248	0.252	0.256	6.30	6.40	6.50
L	0.033	0.037	0.041	0.85	0.95	1.05
L <sub>1</sub>	0.020	0.024	0.028	0.50	0.60	0.70
a	1 <sup>ø</sup>	3 <sup>ø</sup>	5 <sup>ø</sup>	1 <sup>ø</sup>	3 <sup>ø</sup>	5 <sup>ø</sup>
e	0.026 BSC			0.65 BSC		



### Notes:

1. Dimension D & E include mold mismatch and are determined at the mold parting line.
2. General appearance spec. should be based on final visual inspection spec.




# ATOM120\_SOIC20/TSSOP20

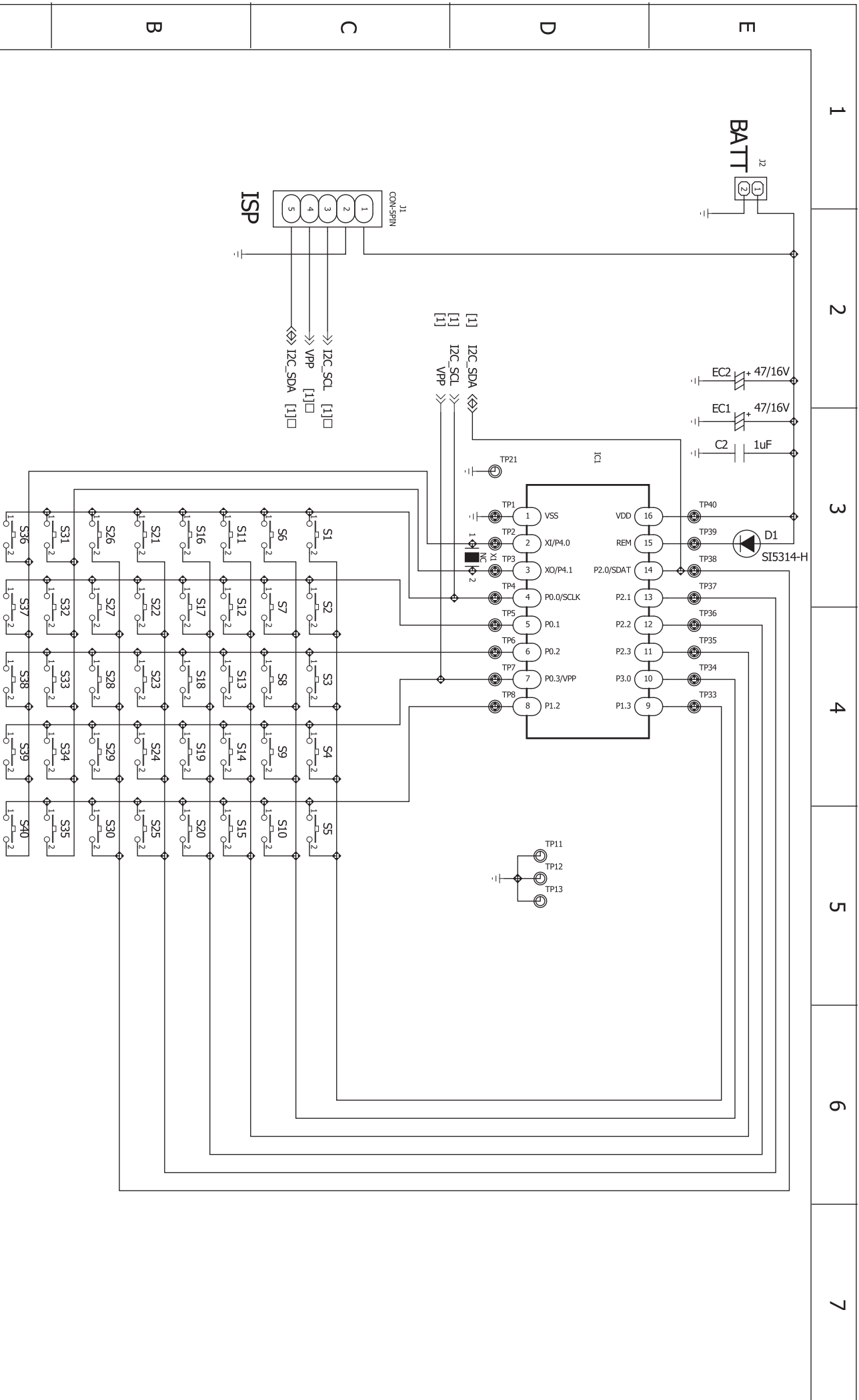
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2				SCALE							
				Version							
				DRAWN.							
				sunhong							
				2016-12-07							
				ATOM120 SOIC20/TSSOP20							
				DSCHMATIC							

**SHEET** 1 / 1

**SCALE** A3 V1.0


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# ATOM120\_TSSOP16

NO. / REVISION NO.	NO. / REVISION NO.	QUANTITY		PART NO.		DESCRIPTION	MATERIAL	COLOR FINISH	NOTE	
1		C	B	A	NO	Version	DRAWN.	DISCHEMATIC		
2		SCALE		Version		DESCRIPTION	MATERIAL	COLOR FINISH	NOTE	
		A3		V1.0		sunhong				
		SHEET		1 / 1		2016-12-07	ATOM120 TSSOP16			
							<b>CORRIVER</b>			